

Ordering number:ENN4601A

勝特力材料 886-3-5753170  
 勝特力电子(上海) 86-21-54151736  
 勝特力电子(深圳) 86-755-83298787  
 Http://www.100y.com.tw

N-Channel Silicon MOSFET

**2SK2161**



## Ultrahigh-Speed Switching Applications

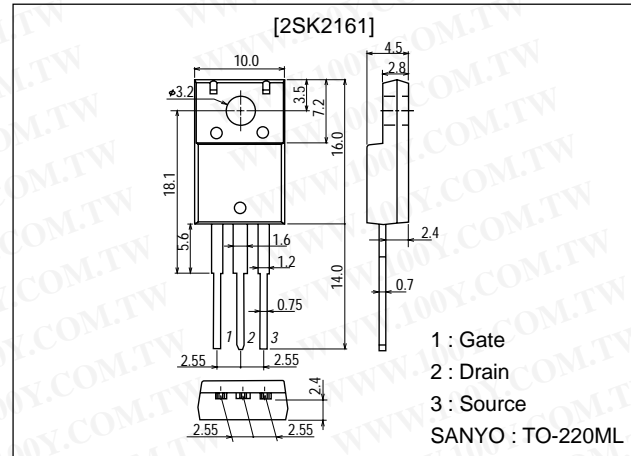
### Features

- Low ON resistance.
- Ultrahigh-speed switching.
- Low-voltage drive.
- Micaless package facilitating mounting.

### Package Dimensions

unit:mm

2063A



### Specifications

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	$V_{DSS}$		200	V
Gate-to-Source Voltage	$V_{GSS}$		$\pm 20$	V
Drain Current (DC)	$I_D$		9	A
Drain Current (Pulse)	$I_{DP}$	$PW \leq 10\mu s$ , duty cycle $\leq 1\%$	36	A
Allowable Power Dissipation	$P_D$		2.0	W
		$T_c = 25^\circ C$	25	W
Channel Temperature	$T_{ch}$		150	$^\circ C$
Storage Temperature	$T_{stg}$		-55 to +150	$^\circ C$

#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 1mA$ , $V_{GS} = 0$	200			V
Gate-to-Source Breakdown Voltage	$V_{(BR)GSS}$	$I_G = \pm 100\mu A$ , $V_{DS} = 0$	$\pm 20$			V
Zero-Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 200V$ , $V_{GS} = 0$			100	$\mu A$
Gate-to-Source Leakage Current	$I_{GSS}$	$V_{GS} = \pm 16V$ , $V_{DS} = 0$			$\pm 10$	$\mu A$
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = 10V$ , $I_D = 1mA$	1.5		2.5	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = 10V$ , $I_D = 4.5A$	3.5	6		S
Static Drain-to-Source ON-State Resistance	$R_{DS(on)}$	$I_D = 4.5A$ , $V_{GS} = 10V$		250	350	$m\Omega$

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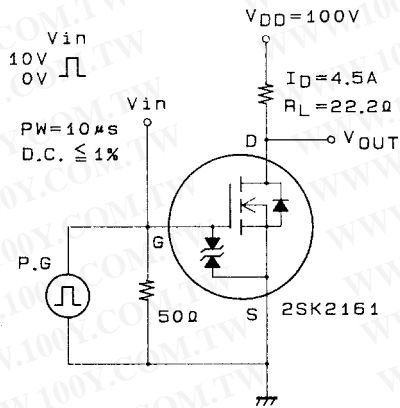
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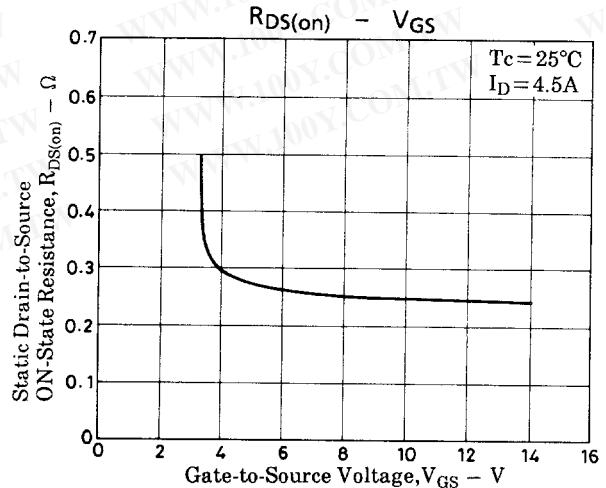
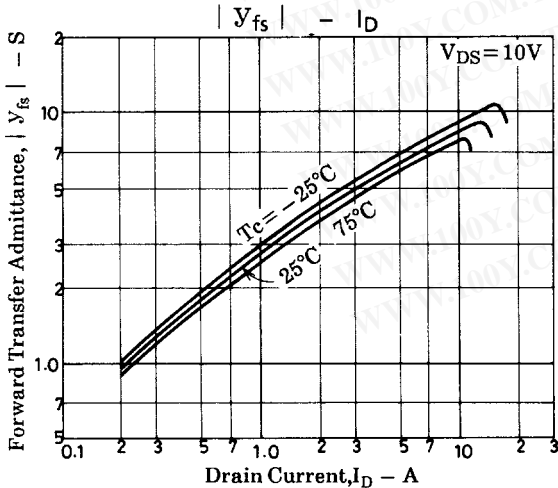
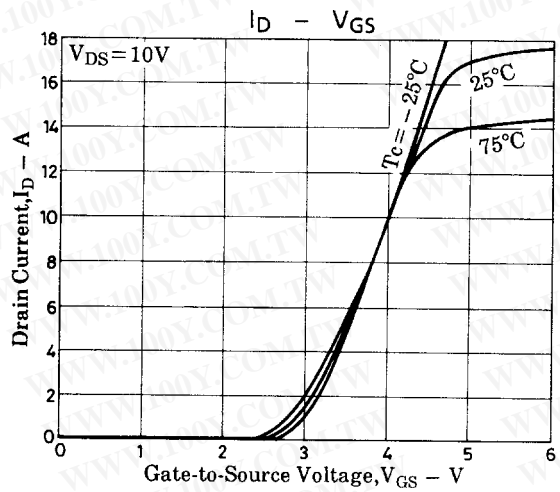
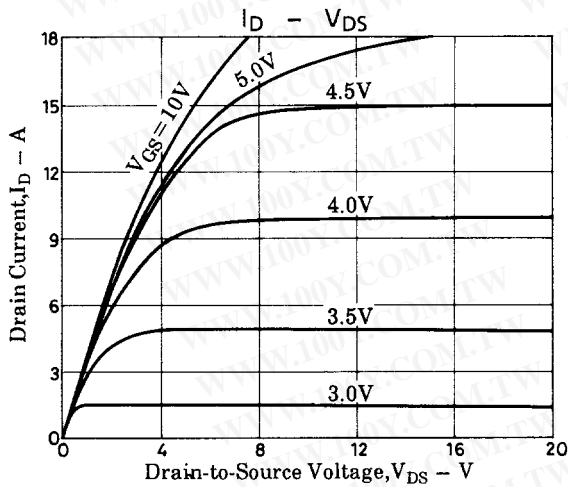
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =20V, f=1MHz		700		pF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =20V, f=1MHz		140		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	V <sub>DS</sub> =20V, f=1MHz		55		pF
Turn-ON Delay Time	t <sub>d(on)</sub>	See specified Test Circuit		14		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit		19		ns
Turn-OFF Delay Time	t <sub>d(off)</sub>	See specified Test Circuit		200		ns
Fall Time	t <sub>f</sub>	See specified Test Circuit		80		ns
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =9A, V <sub>GS</sub> =0		1.0	1.5	V

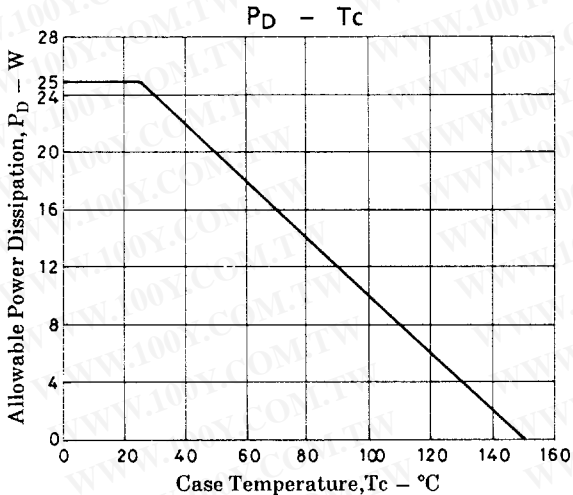
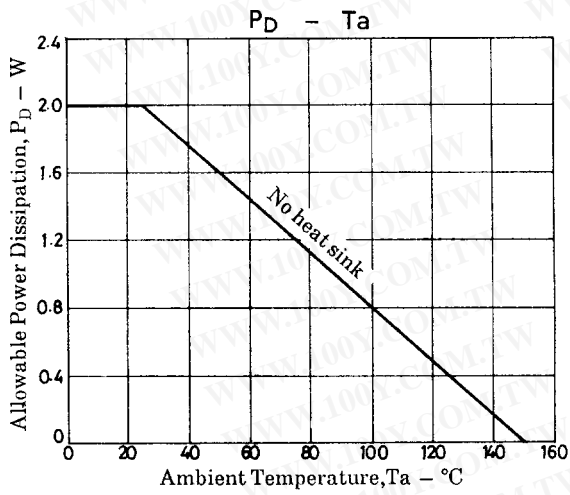
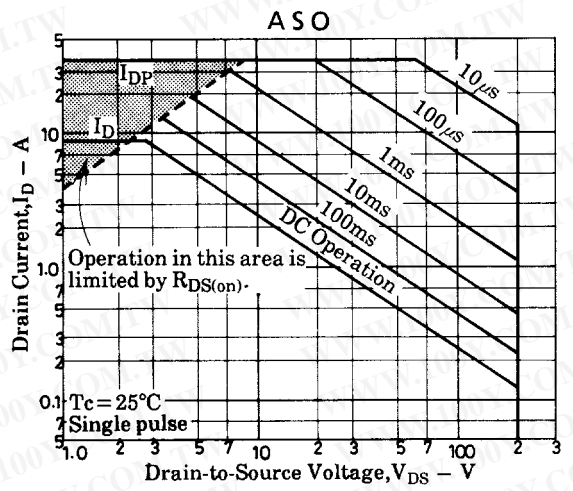
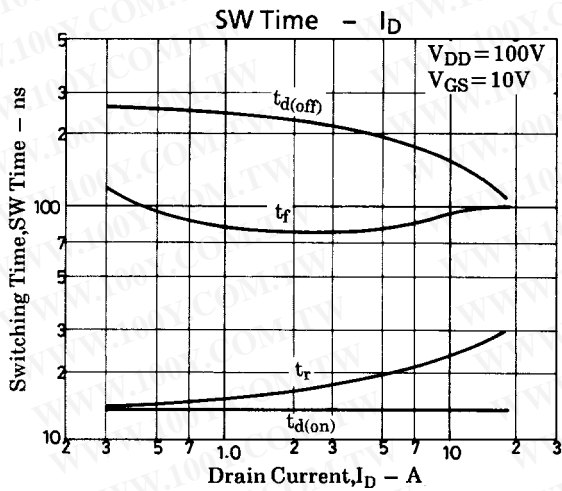
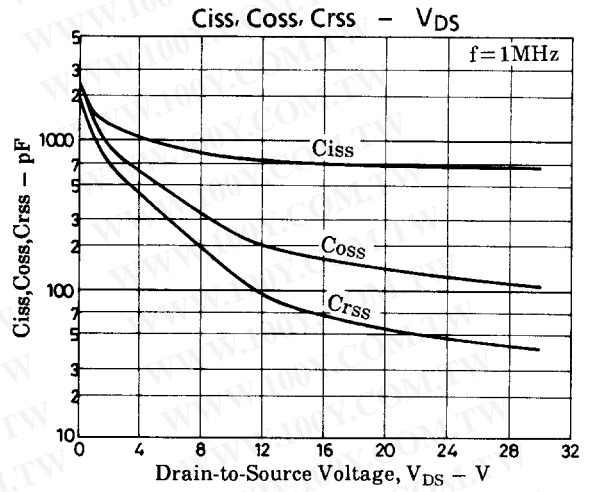
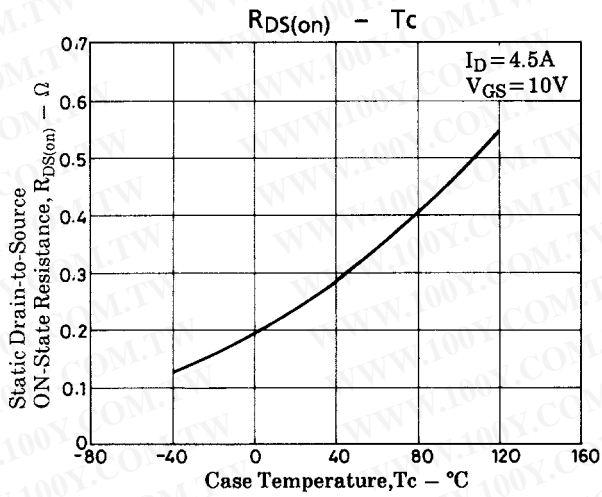
## Switching Time Test Circuit



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